

Principles Of Semiconductor Devices And Heterojunctions By Bart Van Zeghbroeck

Right here, we have countless books **principles of semiconductor devices and heterojunctions by bart van zeghbroeck** and collections to check out. We additionally have enough money variant types and plus type of the books to browse. The tolerable book, fiction, history, novel, scientific research, as capably as various new sorts of books are readily within reach here.

As this principles of semiconductor devices and heterojunctions by bart van zeghbroeck, it ends up visceral one of the favored book principles of semiconductor devices and heterojunctions by bart van zeghbroeck collections that we have. This is why you remain in the best website to look the unbelievable book to have.

Characterization of Semiconductor Heterostructures and Nanostructures - Giovanni Agostini 2011-08-11

In the last couple of decades, high-performance electronic and optoelectronic devices based on semiconductor heterostructures have been required to obtain increasingly strict and well-defined performances, needing a detailed control, at the atomic level, of the structural composition of the buried interfaces. This goal has been achieved by an improvement of the epitaxial growth techniques and by the parallel use of increasingly sophisticated characterization techniques and of refined theoretical models based on ab initio approaches. This book deals with description of both characterization techniques and theoretical models needed to understand and predict the structural and electronic properties of semiconductor heterostructures and nanostructures. - Comprehensive collection of the most powerful characterization techniques for semiconductor heterostructures and nanostructures - Most of the chapters are authored by scientists that are among the top 10 worldwide in publication ranking of the specific field - Each chapter starts with a didactic introduction on the technique - The second part of each chapter deals with a selection of top examples

highlighting the power of the specific technique to analyze the properties of semiconductors

Physics of Semiconductor Devices - Simon M. Sze 2021-03-03

The new edition of the most detailed and comprehensive single-volume reference on major semiconductor devices The Fourth Edition of Physics of Semiconductor Devices remains the standard reference work on the fundamental physics and operational characteristics of all major bipolar, unipolar, special microwave, and optoelectronic devices. This fully updated and expanded edition includes approximately 1,000 references to original research papers and review articles, more than 650 high-quality technical illustrations, and over two dozen tables of material parameters. Divided into five parts, the text first provides a summary of semiconductor properties, covering energy band, carrier concentration, and transport properties. The second part surveys the basic building blocks of semiconductor devices, including p-n junctions, metal-semiconductor contacts, and metal-insulator-semiconductor (MIS) capacitors. Part III examines bipolar transistors, MOSFETs (MOS field-effect transistors), and other field-effect transistors such as JFETs (junction field-effect-transistors) and MESFETs (metal-semiconductor

field-effect transistors). Part IV focuses on negative-resistance and power devices. The book concludes with coverage of photonic devices and sensors, including light-emitting diodes (LEDs), solar cells, and various photodetectors and semiconductor sensors. This classic volume, the standard textbook and reference in the field of semiconductor devices: Provides the practical foundation necessary for understanding the devices currently in use and evaluating the performance and limitations of future devices Offers completely updated and revised information that reflects advances in device concepts, performance, and application Features discussions of topics of contemporary interest, such as applications of photonic devices that convert optical energy to electric energy Includes numerous problem sets, real-world examples, tables, figures, and illustrations; several useful appendices; and a detailed solutions manual for Instructor's only Explores new work on leading-edge technologies such as MODFETs, resonant-tunneling diodes, quantum-cascade lasers, single-electron transistors, real-space-transfer devices, and MOS-controlled thyristors Physics of Semiconductor Devices, Fourth Edition is an indispensable resource for design engineers, research scientists, industrial and electronics engineering managers, and graduate students in the field.

Organic Semiconductor Heterojunctions and Its Application in Organic Light-Emitting Diodes - Dongge Ma 2017-09-21

This book systematically introduces the most important aspects of organic semiconductor heterojunctions, including the basic concepts and electrical properties. It comprehensively discusses the application of organic semiconductor heterojunctions as charge injectors and charge generation layers in organic light-emitting diodes (OLEDs). Semiconductor heterojunctions are the basis for constructing high-performance optoelectronic devices. In recent decades, organic semiconductors have been increasingly used to fabricate heterojunction devices, especially in OLEDs, and the subject has attracted a great deal of attention and evoked many new phenomena and interpretations in the field. This important application is based on the low dielectric constant of organic semiconductors and the weak non-covalent electronic

interactions between them, which means that they easily form accumulation heterojunctions. As we know, the accumulation-type space charge region is highly conductive, which is an important property for highly efficient charge generation in their application as charge injector and charge generation layer in OLEDs. This book serves as a valuable reference for researchers and as a textbook for graduate students focusing on the study and development of OLED for display and lighting. **Springer Handbook of Semiconductor Devices** - Massimo Rudan 2022-11-10

This Springer Handbook comprehensively covers the topic of semiconductor devices, embracing all aspects from theoretical background to fabrication, modeling, and applications. Nearly 100 leading scientists from industry and academia were selected to write the handbook's chapters, which were conceived for professionals and practitioners, material scientists, physicists and electrical engineers working at universities, industrial R&D, and manufacturers. Starting from the description of the relevant technological aspects and fabrication steps, the handbook proceeds with a section fully devoted to the main conventional semiconductor devices like, e.g., bipolar transistors and MOS capacitors and transistors, used in the production of the standard integrated circuits, and the corresponding physical models. In the subsequent chapters, the scaling issues of the semiconductor-device technology are addressed, followed by the description of novel concept-based semiconductor devices. The last section illustrates the numerical simulation methods ranging from the fabrication processes to the device performances. Each chapter is self-contained, and refers to related topics treated in other chapters when necessary, so that the reader interested in a specific subject can easily identify a personal reading path through the vast contents of the handbook.

Lasers: Principles, Types and Applications - K. R. Nambiar 2006
This Book On Lasers Is The Culmination Of Several Years Of Relentless Personal Research, Exhaustive Literature Survey, Critical Analysis Of All The Facets Of The Subject And Interactions With The Subject Experts And Students In India And Abroad, By The Author. This Book Has Been

Very Systematically Structured And Organised. The Subject Has Been Divided Into Three Parts. Part A Deals With All The Established Principles And Theories Of Laser Science Prefixed With A Journey Through The Relevant Areas Of Optics And Modern Physics. Part B Presents A Galaxy Of All The Available Laser Schemes Of The Day, With A Peep Into The Future. Part C Deals With The Myriads Of Applications Of This 'Wonder Beam' In Every Walk Of Life. While Giving An Exhaustive Account About Lasers, The Book Also Covers All The, Relevant Aspects Of Related Subjects Such As Fibre Optics, Holography, Laser Safety Etc. Apart From The Excellent Presentation Of The Topics, As They Unfold, This Book Contains A Rich Fund Of Worked Out Examples And Student Exercises, With Answers. The Language Is Simple And Reader-Friendly, The Treatise Logical, And Even The Intricate Mathematical Derivations And Clear And Lucid. This Book Is Meant To Be A Very Valuable Guide To Students At Graduate And Postgraduate Levels And To Those Working Or Intending To Work In The Field Of Lasers, To Add To What They Already Know. This Is Perhaps The Only Book, At Present, On Lasers By An Indian Author With Such A Vast Coverage Of The Subject Itself And The Associated Disciplines.

The Physics of Semiconductor Devices - R. K. Sharma 2019-01-31

This book disseminates the current knowledge of semiconductor physics and its applications across the scientific community. It is based on a biennial workshop that provides the participating research groups with a stimulating platform for interaction and collaboration with colleagues from the same scientific community. The book discusses the latest developments in the field of III-nitrides; materials & devices, compound semiconductors, VLSI technology, optoelectronics, sensors, photovoltaics, crystal growth, epitaxy and characterization, graphene and other 2D materials and organic semiconductors.

Complete Guide to Semiconductor Devices - Kwok K. Ng 2002-07-25

A definitive and up-to-date handbook of semiconductor devices. Semiconductor devices, the basic components of integrated circuits, are responsible for the rapid growth of the electronics industry over the past fifty years. Because there is a growing need for faster and more complex

systems for the information age, existing semiconductor devices are constantly being studied for improvement, and new ones are being continually invented. As a result, a large number of types and variations of devices are available in the literature. The Second Edition of this unique engineering guide continues to be the only available complete collection of semiconductor devices, identifying 74 major devices and more than 200 variations of these devices. As in the First Edition, the value of this text lies in its comprehensive, yet highly readable presentation and its easy-to-use format, making it suitable for a wide range of audiences. Essential information is presented for a quick, balanced overview. Each chapter is designed to cover only one specific device, for easy and focused reference. Each device is discussed in detail, always including its history, its structure, its characteristics, and its applications. The Second Edition has been significantly updated with eight new chapters, and the material rearranged to reflect recent developments in the field. As such, it remains an ideal reference source for graduate students who want a quick survey of the field, as well as for practitioners and researchers who need quick access to basic information, and a valuable pragmatic handbook for salespeople, lawyers, and anyone associated with the semiconductor industry.

Principles and Analysis of AlGaAs/GaAs Heterojunction Bipolar Transistors - Juin J. Liou 1996

The first book devoted entirely to HBTs, this reference examines the basic concept, standard and advanced structures, noise performance, reliability issues, and simulation. It's main emphasis is on device physics and its mathematical representations, through which the operational characterization of AlGaAs/GaAs HBTs can be understood. It enables device engineers, device researchers, and circuit designers to increase their knowledge of HBT principles and behavior with significantly less literature research time, and to design optimal HBTs with minimal design time. Extensively referenced, with 150 illustrations and 250 equations.

Semiconductor Materials - B.G. Yacobi 2003-01-31

The main objective of this book is to provide an introductory perspective

of the basic principles of semiconductors, being an integrated overview of the basic properties, applications, and characterization of semiconductors in a single volume. This book is suitable for both undergraduate and graduate students, and for researchers, working in a wide variety of fields in physical and engineering sciences, who require an introductory and concise description of the field of semiconductors.

Physics of Semiconductor Devices - Dilip K Roy 2004

Semiconductor Devices and Integrated Electronics - A. G. Milnes
2012-12-06

For some time there has been a need for a semiconductor device book that carries diode and transistor theory beyond an introductory level and yet has space to touch on a wider range of semiconductor device principles and applications. Such topics are covered in specialized monographs numbering many hundreds, but the voluminous nature of this literature limits access for students. This book is the outcome of attempts to develop a broad course on devices and integrated electronics for university students at about senior-year level. The educational prerequisites are an introductory course in semiconductor junction and transistor concepts, and a course on analog and digital circuits that has introduced the concepts of rectification, amplification, oscillators, modulation and logic and switching circuits. The book should also be of value to professional engineers and physicists because of both, the information included and the detailed guide to the literature given by the references. The aim has been to bring some measure of order into the subject area examined and to provide a basic structure from which teachers may develop themes that are of most interest to students and themselves. Semiconductor devices and integrated circuits are reviewed and fundamental factors that control power levels, frequency, speed, size and cost are discussed. The text also briefly mentions how devices are used and presents circuits and comments on representative applications. Thus, the book seeks a balance between the extremes of device physics and circuit design.

The Oxford Solid State Basics - Steven H. Simon 2013-06-20

This is a first undergraduate textbook in Solid State Physics or Condensed Matter Physics. While most textbooks on the subject are extremely dry, this book is written to be much more exciting, inspiring, and entertaining.

SEMICONDUCTOR DEVICES - NANDITA DASGUPTA 2004-01-01
Aimed primarily at the undergraduate students pursuing courses in semiconductor physics and semiconductor devices, this text emphasizes the physical understanding of the underlying principles of the subject. Since engineers use semiconductor devices as circuit elements, device models commonly used in the circuit simulators, e.g. SPICE, have been discussed in detail. Advanced topics such as lasers, heterojunction bipolar transistors, second order effects in BJTs, and MOSFETs are also covered. With such in-depth coverage and a practical approach, practising engineers and PG students can also use this book as a ready reference.

High-Speed Semiconductor Devices - S. N. Sze 1990-08-15
Introduces the physical principles and operational characteristics of high speed semiconductor devices. Intended for use by advanced students as well as professional engineers and scientists involved in semiconductor device research, it includes the most advanced and important topics in high speed semiconductor devices. Initial chapters cover material properties, advanced technologies and novel device building blocks, and serve as the basis for understanding and analyzing devices in subsequent chapters. The following chapters cover a group of closely related devices that includes MOSFETs, MESFETs, heterojunction FETs and permeable-base transistors, hot electron transistors, microwave diodes and photonic devices, among others. Each chapter is self-contained and features a summary section, a discussion of future device trend, and an instructional problem set.

Physics of Semiconductor Devices - Simon M. Sze 2006-12-13
The Third Edition of the standard textbook and reference in the field of semiconductor devices This classic book has set the standard for advanced study and reference in the semiconductor device field. Now completely updated and reorganized to reflect the tremendous advances

in device concepts and performance, this Third Edition remains the most detailed and exhaustive single source of information on the most important semiconductor devices. It gives readers immediate access to detailed descriptions of the underlying physics and performance characteristics of all major bipolar, field-effect, microwave, photonic, and sensor devices. Designed for graduate textbook adoptions and reference needs, this new edition includes: A complete update of the latest developments New devices such as three-dimensional MOSFETs, MODFETs, resonant-tunneling diodes, semiconductor sensors, quantum-cascade lasers, single-electron transistors, real-space transfer devices, and more Materials completely reorganized Problem sets at the end of each chapter All figures reproduced at the highest quality Physics of Semiconductor Devices, Third Edition offers engineers, research scientists, faculty, and students a practical basis for understanding the most important devices in use today and for evaluating future device performance and limitations. A Solutions Manual is available from the editorial department.

Advanced Theory of Semiconductor Devices Karl Hess 2000

Electrical Engineering Advanced Theory of Semiconductor Devices Semiconductor devices are ubiquitous in today's world and are found increasingly in cars, kitchens and electronic door locks, attesting to their presence in our daily lives. This comprehensive book provides the fundamentals of semiconductor device theory from basic quantum physics to computer-aided design. Advanced Theory of Semiconductor Devices will improve your understanding of computer simulation of devices through a thorough discussion of basic equations, their validity, and numerical solutions as they are contained in current simulation tools. You will gain state-of-the-art knowledge of devices used in both III-V compounds and silicon technology. Specially featured are novel approaches and explanations of electronic transport, particularly in p-n junction diodes. Close attention is also given to innovative treatments of quantum-well laser diodes and hot electron effects in silicon technology. This in-depth book is written for engineers, graduate students, and research scientists in solid-state electronics who want to gain a better

understanding of the principles underlying semiconductor devices.

Semiconductor Physics and Devices - Donald A. Neamen 2003

This text aims to provide the fundamentals necessary to understand semiconductor device characteristics, operations and limitations. Quantum mechanics and quantum theory are explored, and this background helps give students a deeper understanding of the essentials of physics and semiconductors.

III-V Microelectronics - J.P. Nougier 2014-05-27

As is well known, Silicon widely dominates the market of semiconductor devices and circuits, and in particular is well suited for Ultra Large Scale Integration processes. However, a number of III-V compound semiconductor devices and circuits have recently been built, and the contributions in this volume are devoted to those types of materials, which offer a number of interesting properties. Taking into account the great variety of problems encountered and of their mutual correlations when fabricating a circuit or even a device, most of the aspects of III-V microelectronics, from fundamental physics to modelling and technology, from materials to devices and circuits are reviewed. Containing contributions from European researchers of international repute this volume is the definitive reference source for anyone interested in the latest advances and results of current experimental research in III-V microelectronics.

Compound Semiconductor Device Physics - Charles N Mellowes

Professor in Engineering Sandip Tiwari 1992

This book provides one of the most rigorous treatments of compound semiconductor device physics yet published. A complete understanding of modern devices requires a working knowledge of low-dimensional physics, the use of statistical methods, and the use of one-, two-, and three-dimensional analytical and numerical analysis techniques. With its systematic and detailed discussion of these topics, this book is ideal for both the researcher and the student. Although the emphasis of this text is on compound semiconductor devices, many of the principles discussed will also be useful to those interested in silicon devices. Each chapter ends with exercises that have been designed to reinforce concepts, to

complement arguments or derivations, and to emphasize the nature of approximations by critically evaluating realistic conditions. One of the most rigorous treatments of compound semiconductor device physics yet published**Essential reading for a complete understanding of modern devices**Includes chapter-ending exercises to facilitate understanding

Introduction to Organic Semiconductor Heterojunctions -

Donghang Yan 2010-11-15

It is well known that most important electronic devices use Schottky junctions and heterojunctions. Unfortunately there is not an advanced book introducing heterojunctions systematically. Introduction to Organic Semiconductor Heterojunctions fills the gap. In this book, the authors provide a comprehensive discussion and systematic introduction on the state-of-the-art technologies as well as application of organic semiconductor heterojunctions. First book to systematically introduce organic heterojunctions Arms readers with theoretical, experimental and applied aspects of organic heterojunctions The Chinese edition of the book is part of the Chinese Academy of Sciences' Distinguished Young Scholar Scientific Book Series Introduction to Organic Semiconductor Heterojunctions is an ideal and valued reference for researchers and graduate students focusing on organic thin film devices like organic light-emitting diodes (OLEDs), organic photovoltaic (OPV) cells, and organic field-effect transistors (OFETs). Instructors can use the book as a supplementary text for a semiconductor physics or organic electronics course, giving students a better feel for the application of organic thin film devices.

III-V Semiconductor Materials and Devices Ref. Malik 2012-12-02

The main emphasis of this volume is on III-V semiconductor epitaxial and bulk crystal growth techniques. Chapters are also included on material characterization and ion implantation. In order to put these growth techniques into perspective a thorough review of the physics and technology of III-V devices is presented. This is the first book of its kind to discuss the theory of the various crystal growth techniques in relation to their advantages and limitations for use in III-V semiconductor devices.

Compound Semiconductor Device Physics - Sandip Tiwari 2013-10-22

This book provides one of the most rigorous treatments of compound semiconductor device physics yet published. A complete understanding of modern devices requires a working knowledge of low-dimensional physics, the use of statistical methods, and the use of one-, two-, and three-dimensional analytical and numerical analysis techniques. With its systematic and detailed**discussion of these topics, this book is ideal for both the researcher and the student. Although the emphasis of this text is on compound semiconductor devices, many of the principles discussed will also be useful to those interested in silicon devices. Each chapter ends with exercises that have been designed to reinforce concepts, to complement arguments or derivations, and to emphasize the nature of approximations by critically evaluating realistic conditions. One of the most rigorous treatments of compound semiconductor device physics yet published**Essential reading for a complete understanding of modern devices**Includes chapter-ending exercises to facilitate understanding

Basic Principles of Electronics Jenkins 2014-05-09

Basic Principles of Electronics, Volume 2: Semiconductors focuses on the properties, applications, and characteristics of semiconductors. The publication first elaborates on conduction in the solid state, conduction and heat, and semiconductors. Discussions focus on extrinsic or impurity semiconductors, electrons and holes, effect of temperature on the conductivity, mean free path, Joule heating effect, "vacancies" in crystals, and Drude's theory of metallic conduction. The text then ponders on semiconductor technology and simple devices, transistor, and transistor production and characteristics. Topics include strain gauges, thermistors, thermoelectric semiconductors, crystal preparation, photoconductors, and the Hall effect. The book elaborates on special devices, processes, and uses, common transistor circuitry, and a low-frequency equivalent circuit for common base, including radiation detection, optoelectronics, field effect transistors, sonar amplifier, oscillators, and multi-stage amplifiers. The publication is highly recommended for technical college students and researchers wanting to study semiconductors.

Semiconductor Material and Device Characterization - Dieter K. Schroder 2015-06-29

This Third Edition updates a landmark text with the latest findings. The Third Edition of the internationally lauded *Semiconductor Material and Device Characterization* brings the text fully up-to-date with the latest developments in the field and includes new pedagogical tools to assist readers. Not only does the Third Edition set forth all the latest measurement techniques, but it also examines new interpretations and new applications of existing techniques. *Semiconductor Material and Device Characterization* remains the sole text dedicated to characterization techniques for measuring semiconductor materials and devices. Coverage includes the full range of electrical and optical characterization methods, including the more specialized chemical and physical techniques. Readers familiar with the previous two editions will discover a thoroughly revised and updated Third Edition, including:

- Updated and revised figures and examples reflecting the most current data and information
- 260 new references offering access to the latest research and discussions in specialized topics
- New problems and review questions at the end of each chapter to test readers' understanding of the material
- In addition, readers will find fully updated and revised sections in each chapter. Plus, two new chapters have been added:

- Charge-Based and Probe Characterization** introduces charge-based measurement and Kelvin probes. This chapter also examines probe-based measurements, including scanning capacitance, scanning Kelvin force, scanning spreading resistance, and ballistic electron emission microscopy.
- Reliability and Failure Analysis** examines failure times and distribution functions, and discusses electromigration, hot carriers, gate oxide integrity, negative bias temperature instability, stress-induced leakage current, and electrostatic discharge.

Written by an internationally recognized authority in the field, *Semiconductor Material and Device Characterization* remains essential reading for graduate students as well as for professionals working in the field of semiconductor devices and materials. An Instructor's Manual presenting detailed solutions to all the problems in the book is available from the

Wiley editorial department.

Principles of Solar Cells, LEDs and Related Devices - Adrian Kitai 2018-11-05

The second edition of the text that offers an introduction to the principles of solar cells and LEDs, revised and updated. The revised and updated second edition of *Principles of Solar Cells, LEDs and Related Devices* offers an introduction to the physical concepts required for a comprehensive understanding of p-n junction devices, light emitting diodes and solar cells. The author - a noted expert in the field - presents information on the semiconductor and junction device fundamentals and extends it to the practical implementation of semiconductors in both photovoltaic and LED devices. In addition, the text offers information on the treatment of a range of important semiconductor materials and device structures including OLED devices and organic solar cells. This second edition contains a new chapter on the quantum mechanical description of the electron that will make the book accessible to students in any engineering discipline. The text also includes a new chapter on bipolar junction and junction field effect transistors as well as expanded chapters on solar cells and LEDs that include more detailed information on high efficiency devices. This important text: Offers an introduction to solar cells and LEDs, the two most important applications of semiconductor diodes. Provides a solid theoretical basis for p-n junction devices. Contains updated information and new chapters including better coverage of LED out-coupling design and performance and improvements in OLED efficiency. Presents student problems at the end of each chapter and worked example problems throughout the text. Written for students in electrical engineering, physics and materials science and researchers in the electronics industry, *Principles of Solar Cells, LEDs and Related Devices* is the updated second edition that offers a guide to the physical concepts of p-n junction devices, light emitting diodes and solar cells.

Quantum Physics of Semiconductor Materials and Devices - Debdeep Jena 2022-06-25

"Quantum Phenomena do not occur in a Hilbert space. They occur in a

laboratory". - Asher Peres Semiconductor physics is a laboratory to learn and discover the concepts of quantum mechanics and thermodynamics, condensed matter physics, and materials science, and the payoffs are almost immediate in the form of useful semiconductor devices. Debdeep Jena has had the opportunity to work on both sides of the fence - on the fundamental materials science and quantum physics of semiconductors, and in their applications in semiconductor electronic and photonic devices. In Quantum Physics of Semiconductors and Nanostructures, Jena uses this experience to make each topic as tangible and accessible as possible to students at all levels. Consider the simplest physical processes that occur in semiconductors: electron or hole transport in bands and over barriers, collision of electrons with the atoms in the crystal, or when electrons and holes annihilate each other to produce a photon. The correct explanation of these processes require a quantum mechanical treatment. Any shortcuts lead to misconceptions that can take years to dispel, and sometimes become roadblocks towards a deeper understanding and appreciation of the richness of the subject. A typical introductory course on semiconductor physics would then require prerequisites of quantum mechanics, statistical physics and thermodynamics, materials science, and electromagnetism. Rarely would a student have all this background when (s)he takes a course of this nature in most universities. Jena's work fills in these gaps and gives students the background and deeper understanding of the quantum physics of semiconductors and nanostructures.

Semiconductor Physical Electronics - Sheng S. Li 2012-12-06

The purpose of this book is to provide the reader with a self-contained treatment of fundamental solid state and semiconductor device physics. The material presented in the text is based upon the lecture notes of a one-year graduate course sequence taught by this author for many years in the Department of Electrical Engineering of the University of Florida. It is intended as an introductory textbook for graduate students in electrical engineering. However, many students from other disciplines and backgrounds such as chemical engineering, materials science, and physics have also taken this course sequence, and will be interested in

the material presented herein. This book may also serve as a general reference for device engineers in the semiconductor industry. The present volume covers a wide variety of topics on basic solid state physics and physical principles of various semiconductor devices. The main subjects covered include crystal structures, lattice dynamics, semiconductor statistics, energy band theory, excess carrier phenomena and recombination mechanisms, carrier transport and scattering mechanisms, optical properties, photoelectric effects, metal-semiconductor devices, the p-n junction diode, bipolar junction transistor, MOS devices, photonic devices, quantum effect devices, and high speed III-V semiconductor devices. The text presents a unified and balanced treatment of the physics of semiconductor materials and devices. It is intended to provide physicists and materials scientists with more device backgrounds, and device engineers with a broader knowledge of fundamental solid state physics.

Semiconductor Devices, Physics and Technology - S. M. Sze 2013

Principles of Semiconductor Devices - Sima Dimitrijevic 2012

"This dynamic text applies physics concepts and equations to practical, real-world applications of semiconductor device theory"--

Semiconductor Materials - B.G. Yacobi 2006-04-18

The technological progress is closely related to the developments of various materials and tools made of those materials. Even the different ages have been defined in relation to the materials used. Some of the major attributes of the present-day age (i.e., the electronic materials' age) are such common tools as computers and fiber-optic telecommunication systems, in which semiconductor materials provide vital components for various micro-electronic and optoelectronic devices in applications such as computing, memory storage, and communication. The field of semiconductors encompasses a variety of disciplines. This book is not intended to provide a comprehensive description of a wide range of semiconductor properties or of a continually increasing number of the semiconductor device applications. Rather, the main purpose of this book is to provide an introductory perspective on the basic principles

of semiconductor materials and their applications that are described in a relatively concise format in a single volume. Thus, this book should especially be suitable as an introductory text for a single course on semiconductor materials that may be taken by both undergraduate and graduate engineering students. This book should also be useful, as a concise reference on semiconductor materials, for researchers working in a wide variety of fields in physical and engineering sciences.

Semiconductor Power Devices - Josef Lutz 2018-02-16

Halbleiter-Leistungsbaulemente sind das Kernstück der Leistungselektronik. Sie bestimmen die Leistungsfähigkeit und machen neuartige und verlustarme Schaltungen erst möglich. In dem Band wird neben den Halbleiter-Leistungsbaulementen selbst auch die Aufbau- und Verbindungstechnik behandelt: von den physikalischen Grundlagen und der Herstellungstechnologie über einzelne Bauelemente bis zu thermomechanischen Problemen, Zerstörungsmechanismen und Störungseffekten. Die 2., überarbeitete Auflage berücksichtigt technische Neuerungen und Entwicklungen.

The Physics and Fabrication of Microstructures and Microdevices

- Michael J. Kelly 2012-12-06

les Houches This Winter School on "The Physics and Fabrication of Microstructures" originated with a European industrial decision to investigate in some detail the potential of custom-designed microstructures for new devices. Beginning in 1985, GEC and THOMSON started a collaboration on these subjects, supported by an ESPRIT grant from the Commission of the European Community. To the outside observer of the whole field, it appears clear that the world effort is very largely based in the United States and Japan. It also appears that cooperation and dissemination of results are very well organised outside Europe and act as a major influence on the development of new concepts and devices. In Japan, a main research programme of the Research and Development for Basic Technology for Future Industries is focused on "Future Electron Devices". In Japan and in the United States, many workshops are organised annually in order to bring together the major specialists in industry and academia, allowing fast dissemination of

advances and contacts for setting up cooperative efforts.

Solar Cell Device Physics - Stephen Fonash 2012-12-02

Solar Cell Device Physics offers a balanced, in-depth qualitative and quantitative treatment of the physical principles and operating characteristics of solar cell devices. Topics covered include photovoltaic energy conversion and solar cell materials and structures, along with homojunction solar cells. Semiconductor-semiconductor heterojunction cells and surface-barrier solar cells are also discussed. This book consists of six chapters and begins by introducing the reader to the basic physical principles and materials properties that are the foundations of photovoltaic energy conversion, with emphasis on various photovoltaic devices capable of efficiently converting solar energy into usable electrical energy. The electronic and optical properties of crystalline, polycrystalline, and amorphous materials with both organic and inorganic materials are considered, together with the manner in which these properties change from one material class to another and the implications of such changes for photovoltaics. Generation, recombination, and bulk transport are also discussed. The two mechanisms of photocarrier collection in solar cells, drift and diffusion, are then compared. The remaining chapters focus on specific solar cell device classes defined in terms of the interface structure employed: homojunctions, semiconductor-semiconductor heterojunctions, and surface-barrier devices. This monograph is appropriate for use as a textbook for graduate students in engineering and the sciences and for seniors in electrical engineering and applied physics, as well as a reference book for those actively involved in solar cell research and development.

Advanced Semiconductor Materials and Devices S.M. Gupta
2015-08-20

This book presents the latest developments in semiconducting materials and devices, providing up-to-date information on the science, processes, and applications in the field. A wide range of topics are covered, including optoelectronic devices, metal-semiconductor junctions, heterojunctions, MISFETs, LEDs, semiconductor lasers, photodiodes,

switching diodes, tunnel diodes, Gunn diodes, solar cells, varactor diodes, IMPATT diodes, and advanced semiconductors. Detailed attention is paid to advanced and futuristic materials. In addition, clear explanations are provided of, for example, electron theories, high-field effects, the Hall effect, transit-time effects, drift and diffusion, breakdown mechanisms, equilibrium and transient conditions, switching, and biasing. The book is designed to meet the needs of undergraduate engineering students and will also be very useful for postgraduate students; it will assist in preparation for examinations at colleges and universities and for other examinations in engineering. Practice questions are therefore presented in both essay and multiple choice format, and many solved examples and unsolved problems are included.

Introduction to Semiconductor Device Modelling - Christopher M. Snowden 1998

This book deals mainly with physical device models which are developed from the carrier transport physics and device geometry considerations. The text concentrates on silicon and gallium arsenide devices and includes models of silicon bipolar junction transistors, junction field effect transistors (JFETs), MESFETs, silicon and GaAs MESFETs, transferred electron devices, pn junction diodes and Schottky varactor diodes. The modelling techniques of more recent devices such as the heterojunction bipolar transistors (HBT) and the high electron mobility transistors are discussed. This book contains details of models for both equilibrium and non-equilibrium transport conditions. The modelling Technique of Small-scale devices is discussed and techniques applicable to submicron-dimensioned devices are included. A section on modern quantum transport analysis techniques is included. Details of essential numerical schemes are given and a variety of device models are used to illustrate the application of these techniques in various fields.

Silicon-germanium Heterojunction Bipolar Transistors - John D. Cressler 2003

This informative, new resource presents the first comprehensive treatment of silicon-germanium heterojunction bipolar transistors (SiGe HBTs). It offers you a complete, from-the-ground-up understanding of

SiGe HBT devices and technology, from a very broad perspective. The book covers motivation, history, materials, fabrication, device physics, operational principles, and circuit-level properties associated with this new cutting-edge semiconductor device technology. Including over 400 equations and more than 300 illustrations, this hands-on reference shows you in clear and concise language how to design, simulate, fabricate, and measure a SiGe HBT.

Principles of Solar Cells, LEDs and Diodes - Adrian Kitai 2011-09-13

The book will cover the two most important applications of semiconductor diodes - solar cells and LEDs - together with quantitative coverage of the physics of the PN junction at the senior undergraduate level. It will include: Review of semiconductor physics Introduction to PN diodes The solar cell Physics of efficient conversion of sunlight into electrical energy Semiconductor solar cell materials and device physics Advanced solar cell materials and devices The light emitting diode Physics of efficient conversion of electrical energy into light Semiconductor light emitting diode materials and device physics Advanced light emitting diode materials and devices

Fundamentals of Semiconductors Peter YU 2007-05-08

Excellent bridge between general solid-state physics textbook and research articles packed with providing detailed explanations of the electronic, vibrational, transport, and optical properties of semiconductors "The most striking feature of the book is its modern outlook ... provides a wonderful foundation. The most wonderful feature is its efficient style of exposition ... an excellent book." Physics Today "Presents the theoretical derivations carefully and in detail and gives thorough discussions of the experimental results it presents. This makes it an excellent textbook both for learners and for more experienced researchers wishing to check facts. I have enjoyed reading it and strongly recommend it as a text for anyone working with semiconductors ... I know of no better text ... I am sure most semiconductor physicists will find this book useful and I recommend it to them." Contemporary Physics Offers much new material: an extensive appendix about the important and by now well-established, deep center known as the DX

center, additional problems and the solutions to over fifty of the problems at the end of the various chapters.

Heterojunction Bipolar Transistors for Circuit Design - Jianjun Gao
2015-04-27

A highly comprehensive summary on circuit related modeling techniques and parameter extraction methods for heterojunction bipolar transistors Heterojunction Bipolar Transistor (HBT) is one of the most important devices for microwave applications. The book details the accurate device modeling for HBTs and high level IC design using HBTs Provides a valuable reference to basic modeling issues and specific semiconductor device models encountered in circuit simulators, with a thorough reference list at the end of each chapter for onward learning Offers an overview on modeling techniques and parameter extraction methods for heterojunction bipolar transistors focusing on circuit simulation and design Presents electrical/RF engineering-related theory and tools and include equivalent circuits and their matrix descriptions, noise, small and large signal analysis methods

Principles of Solar Cells, LEDs and Diodes - Adrian Kitai 2011-08-24

This textbook introduces the physical concepts required for a comprehensive understanding of p-n junction devices, light emitting diodes and solar cells. Semiconductor devices have made a major impact on the way we work and live. Today semiconductor p-n junction diode

devices are experiencing substantial growth: solar cells are used on an unprecedented scale in the renewable energy industry; and light emitting diodes (LEDs) are revolutionizing energy efficient lighting. These two emerging industries based on p-n junctions make a significant contribution to the reduction in fossil fuel consumption. This book covers the two most important applications of semiconductor diodes - solar cells and LEDs - together with quantitative coverage of the physics of the p-n junction. The reader will gain a thorough understanding of p-n junctions as the text begins with semiconductor and junction device fundamentals and extends to the practical implementation of semiconductors in both photovoltaic and LED devices. Treatment of a range of important semiconductor materials and device structures is also presented in a readable manner. Topics are divided into the following six chapters: • Semiconductor Physics • The PN Junction Diode • Photon Emission and Absorption • The Solar Cell • Light Emitting Diodes • Organic Semiconductors, OLEDs and Solar Cells Containing student problems at the end of each chapter and worked example problems throughout, this textbook is intended for senior level undergraduate students doing courses in electrical engineering, physics and materials science. Researchers working on solar cells and LED devices, and those in the electronics industry would also benefit from the background information the book provides.